

306CNQ200

Technical Data Data Sheet N1217, Rev. C

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306CNQ200 SCHOTTKY RECTIFIER



Features

- 175[°]C T_J operation
- Center tap module
- High purity, high temperature epoxy encapsulation for
- enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Baseplate: Nickel plated; Terminals: Nickel plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

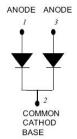
- High current switching power supply
- Plating power supply
- Free-Wheeling diodes
- Reverse battery protection
- Converters
- UPS System
- Welding

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	200	V
Average Rectified Forward Current	I _{F(AV)}	50% duty cycle @T _c =121°C, rectangular wave form	150(Per Leg) 300(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current (Per Leg)	I _{FSM}	8.3 ms, half Sine pulse	3840	А

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Circuit Diagram





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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 150A, Pulse, T _J = 25 °C @ 300A, Pulse, T _J = 25 °C	0.84 -	0.86 1.03	V
	V _{F2}	@ 150A, Pulse, T _J = 125 °C @ 300A, Pulse, T _J = 125 °C	0.71 -	0.76 0.86	V
Reverse Current(Per Leg)*	I _{R1}	$@V_R = rated V_{R, T_J} = 25 \circ C$	0.0001	10	mA
	I _{R2}	$@V_R = rated V_{R,} T_J = 125 \circ C$	0.8	90	mA
Junction Capacitance(Per leg)	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	2300	3500	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/µs

* Pulse width < 300 μs, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification		Units
Junction Temperature	TJ	-	-55 to +175		°C
Storage Temperature	T _{stg}	-	-55 to +175		°C
Typical Thermal Resistance Junction to Case(Per leg)	$R_{ ext{ heta}JC}$	DC operation	0.40		°C/W
Typical Thermal Resistance Junction to Case(Per package)	$R_{ ext{ heta}JC}$	DC operation	0.20		°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ hetacs}$	Mounting surface, smooth and greased	0.10		°C/W
Mounting Torque	Τ _M	-	Mounting Torque Terminal Torque	24(min) 35(max) 35(min) 46(max)	Kg-cm
Approximate Weight	wt	-	79		g
Case Style	PRM4 Non-Isolated				

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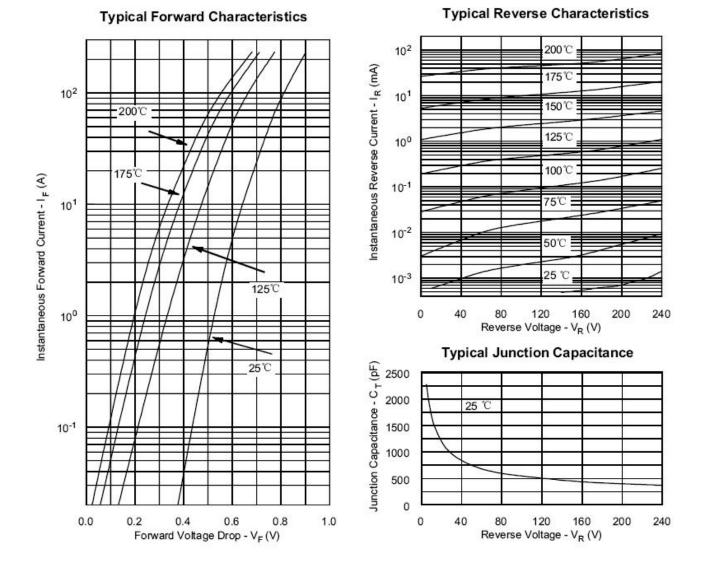


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Ratings and Characteristics Curves



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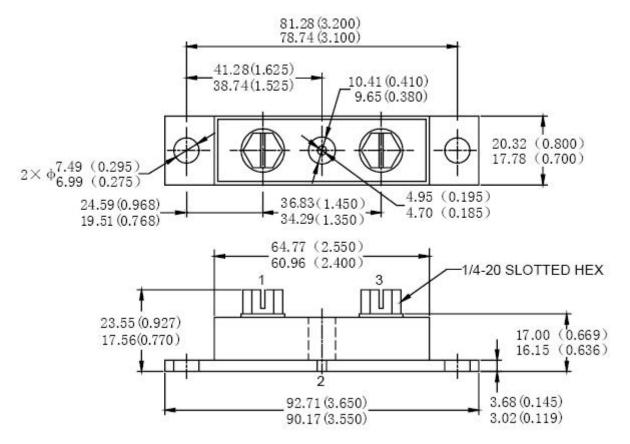


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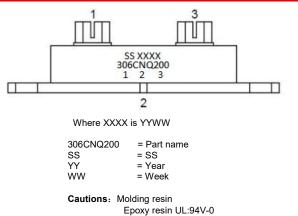
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Mechanical Dimensions PRM4 Non-Isolated(Millimeters/Inches)



Marking Diagram



Ordering Information

Device	Package	Shipping	
306CNQ200	PRM4(Non- Isolated) (Pb-Free)	9 pcs/box	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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